

# Taeseok Kim

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/11988161/publications.pdf>

Version: 2024-02-01

7

papers

98

citations

1937685

4

h-index

1872680

6

g-index

7

all docs

7

docs citations

7

times ranked

130

citing authors

#	ARTICLE	IF	CITATIONS
1	Magnetic properties of ion implanted $\text{Ge}_{1-x}\text{Mn}_x$ thin films solidified through pulsed laser melting. Journal of Applied Physics, 2011, 109, 093917.	2.5	8
2	Room-temperature photoresponse of Schottky photodiodes based on $\text{GaN}_x\text{As}_{1-x}$ synthesized by ion implantation and pulsed-laser melting. Applied Physics Letters, 2010, 97, 151103.	3.3	1
3	Heat flow model for pulsed laser melting and rapid solidification of ion implanted GaAs. Journal of Applied Physics, 2010, 108, 013508.	2.5	16
4	Two dimensionally patterned $\text{GaN}_x\text{As}_{1-x}/\text{GaAs}$ nanostructures using N+ implantation followed by pulsed laser melting. Applied Physics Letters, 2008, 93, 102117.	3.3	4
5	Composition dependence of Schottky barrier heights and bandgap energies of $\text{GaN}_x\text{As}_{1-x}$ synthesized by ion implantation and pulsed-laser melting. Journal of Applied Physics, 2008, 104, .	2.5	11
6	Dielectric Properties Analysis in Paraelectric $\text{ZrTiO}_4$ Thin Films. Materials Research Society Symposia Proceedings, 2001, 666, 371.	0.1	0
7	Correlation between strain and dielectric properties in $\text{ZrTiO}_4$ thin films. Applied Physics Letters, 2000, 76, 3043-3045.	3.3	58